
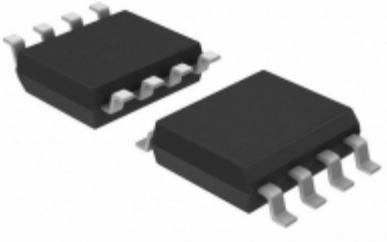








	<p><b>SI4322DY-T1-E3</b></p>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">SI4322DY-T1-E3</a></p> <hr/> <p><b>Hersteller / Marke:</b> <a href="#">Vishay / Siliconix</a></p> <hr/> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 30V 18A 8-SOIC</p> <hr/> <p><b>Datenblätter:</b>  <a href="#">SI4322DY-T1-E3.pdf</a></p> <hr/> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <hr/> <p><b>Lagerzustand:</b> New original, 34580 pcs Stock Available.</p> <hr/> <p><b>Liefern von:</b> Hong Kong</p> <hr/> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	<a href="#">SI4322DY-T1-E3</a>
Hersteller	<a href="#">Vishay / Siliconix</a>
Beschreibung	MOSFET N-CH 30V 18A 8-SOIC
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	34580 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SO
Verlustleistung (max)	3.1W (Ta), 5.4W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	18A (Tc)
Rds On (Max) @ Id, Vgs	8.5 mOhm @ 15A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	38nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1640pF @ 15V
Verpackung	Tape & Reel (TR)













SI4322DY-T1-E3 ist neu im Original, Suche SI4322DY-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI4322DY-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI4322DY-T1-E3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SI4322DY-T1</b> VISHAY VISHAY SO-8</p>	 <p><b>SI4324DY-T1-E3</b> Vishay / Siliconix MOSFET N-CH 30V 36A 8-SOIC</p>	 <p><b>SI4322-A0-FTR</b> Energy Micro (Silicon Labs) IC RX FSK UNI 868/915MHZ 16TSSOP</p>	 <p><b>SI4322-FT</b> SI SI4322-FT SI</p>
 <p><b>SI4322-A1-FT</b> Energy Micro (Silicon Labs) IC RCVR FSK 915MHZ 3.8V 16- TSSOP</p>	 <p><b>SI4322-A0-FT</b> Energy Micro (Silicon Labs) IC RX FSK UNI 868/915MHZ 16TSSOP</p>	 <p><b>SI4322DY-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 30V 18A 8-SOIC</p>	 <p><b>SI4324DY</b> VIS SI4324DY VIS</p>

heiße Teile

Mehr

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|---|---|---|--|--|
|  SI4228DY-T1-GE3 |  SI4228DY-T1-GE3   |  SI4232DY.       |  SI4276DY-T1-E3  |  SI4276DY-T1-E3   |
|  SI4282DVP       |  SI4286DY          |  SI4286DY-T1-GE3 |  SI4286DY-T1-GE3 |  SI4288DY         |
|  SI4288DY-T1-GE3 |  SI4288DY-T1-GE3   |  SI4300-BM       |  SI4300-E-BM     |  SI4300DY-T1-E3   |
|  SI4308DY-T1     |  SI4308DY-T1-E3    |  SI4311-B21-GMR  |  SI4320-J1-FTR   |  SI4320DY         |
|  SI4320DY-T1-E3  |  SI4320DY-T1-E3    |  SI4322-A0-FT    |  SI4322-A0-FTR   |  SI4322DY-T1-E3   |
|  SI4324DY        |  SI4324DY-T1-E3    |  SI4324DY-T1-E3  |  SI4326DY-T1-E3  |  SI4330BDY-T1-GE3 |
|  SI4330DY-T1     |  SI4330DY-T1-E3    |  SI4330DY-T1-E3  |  SI4330DY-T1-E3. |  SI4334DY-T1-E3   |
|  SI4336DY        |  SI4336DY-E3       |  SI4336DY-T1-E3  |  SI4336DY-T1-E3  |  SI4340CDY-T1-E3  |
|  SI4340CDY-T1-E3 |  SI4340CDY-T1-E3-S |  SI4340DY        |  SI4340DY-T1     |  SI4340DY-T1-E3   |
|  SI4340DY-T1-E3  |  SI4346DY          |  SI4346DY-T1-E3  |  SI4346DY-T1-E3  |  SI4346DY-T1-GE3  |

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